

The background is a solid blue color with a pattern of faint, light blue arrows pointing upwards and to the right. In the upper half, there are several overlapping, white-outlined geometric shapes that resemble 3D rectangular blocks or prisms, arranged in a staggered, receding perspective.

LHC UPGRADE DETECTOR DEMO PROPOSAL

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Business from technology

OUTLINE

- Estimates for the upgrade: ATLAS & CMS
- Status of detector technologies
- Detector Demonstarot
- Discussion

ATLAS

Phase 1 (pixels, $\sim 0,3 \text{ m}^2$)

- 3D or thin planar pixels
- Thickness $< 200 \text{ um}$

Pixels ($\sim 5 \text{ m}^2$)

- 3D (1&2) or thin planar pixels
- Thickness $< 200 \text{ um}$

Short strips ($\sim 60 \text{ m}^2$)

- Thin planar short strips
- Thickness $\sim 250 \text{ um}$

Long strips ($\sim 100 \text{ m}^2$)

- Planar long strips
- Thickness $\sim 250 \text{ um}$

CMS

Phase 1 (pixels, $\sim 2 \text{ m}^2$)

- Thin planar pixels
- Thickness $< 200 \text{ um}$

Pixels ($2-4 \text{ m}^2$)

- 3D (1&2) or thin planar pixels
- Thickness $< 200 \text{ um}$

Short strips ($40-60 \text{ m}^2$)

- Thin planar short strips
- Thickness $< 200 \text{ um}$

Long strips ($110-190 \text{ m}^2$)

- Planar long strips
- Thickness $< 300 \text{ um}$

Status of the state-of-the-art

- Existing ATLAS-3D collaboration for 3D and full 3D edgeless detector demos
 - ~10 m² of silicon
 - Research facilities, 100 or 150 mm wafers
 - Aim at inner tracker upgrade
- Existing long strip demonstrators from Hamamatsu on 150 mm wafers with 300 um thickness
 - 200-300 m² of silicon
 - Industry, 150 or 200 mm wafers
 - Aim at long strip upgrade
- Lack of technology in thin (<200 um) short strip detector fabrication, ROCs and hybridization
 - 100-120 m² of silicon
 - Research facilities and technology transfer to industry
 - 100 and 150 mm wafers

Detector demonstrator

- Fill the missing gap in the upgrade technologies
- Thin detector fabrication on 100 mm and 150 mm wafers
 - Low cost -> no support wafer possibility
 - Edge of the wafer assumed to be critical for wafer breaking
 - Trials for thickness of 150 μm and 200 μm on 100 mm on 150 mm wafers, respectively
- Possible technology transfer to industry
- Successful demonstrator will promote Silicon Sensor Alliance as a whole
- Achieves competitive edge over Hamamatsu also in long strip detector deal



VTT creates business from technology

